

General Description

The WSP4882 is the highest performance trench N-ch MOSFET with extreme high cell density, which provide excellent R_{DSON} and gate chargens for most of the synchronous buck converter applications .

The WSP4882 meet the RoHS and Green Product requirement,100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

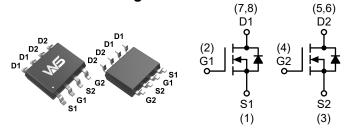
Product Summery

BV _{DSS}	R _{DSON}	l _D
30V	20mΩ	8.0A

Application

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

SOP-8L Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _C =25℃	Continuous Drain Current, V _{GS} @ 10V ¹	8.0	Α
I _D @T _C =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	7.0	Α
I _{DM}	Pulsed Drain Current ²	40	А
EAS	Single Pulse Avalanche Energy ³	20	mJ
I _{AS}	Avalanche Current	9	Α
P _D @T _A =25℃	Total Power Dissipation⁴	2.0	W
T _{STG}	Storage Temperature Range	-55 to 150	${\mathbb C}$
T _J	Operating Junction Temperature Range	-55 to 150	$^{\circ}$

Thermal Data

Symbol	Parameter		Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-ambient ¹		90	°C/W
R _{eJC}	Thermal Resistance Junction-Case ¹		50	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =1mA		0.034		V/°C
В	Static Drain-Source On-Resistance ²	V_{GS} =10V , I_D =8A		20 26		m0
R _{DS(ON)}	Static Dialii-Source On-Resistance	V _{GS} =4.5V , I _D =5A		28	32	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V _{GS} =V _{DS} . In =250uA	1.5	1.8	2.5	٧
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	V _{GS} -V _{DS} , I _D -250UA		-5.8		mV/℃
	Drain Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =25°C			1	
I _{DSS}	Drain-Source Leakage Current	V_{DS} =24V , V_{GS} =0V , T_{J} =55 $^{\circ}$ C			5	uA
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA
gfs	Forward Transconductance	V_{DS} =5 V , I_{D} =8 A		6		S
R_g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.7	2.5	Ω
Qg	Total Gate Charge (4.5V)			6	8.4	
Q_gs	Gate-Source Charge	V_{DS} =15V , V_{GS} =4.5V , I_{D} =8A		1.5		nC
Q_{gd}	Gate-Drain Charge			2.5		
$T_{d(on)}$	Turn-On Delay Time			6	8.8	
T _r	Rise Time	V_{DD} =15V , V_{GEN} =10V , R_{G} =6 Ω		8.2	14	
T _{d(off)}	Turn-Off Delay Time	I _D =1A,R _L =15Ω		4	8	ns
T _f	Fall Time			16	24	
C _{iss}	Input Capacitance			560		
C _{oss}	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		92		pF
C _{rss}	Reverse Transfer Capacitance			55		

Guaranteed Avalanche Characteristics

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy ⁵	V _{DD} =25V , L=0.5mH , I _{AS} =8A	18			mJ

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current ^{1,6}	V _G =V _D =0V , Force Current			2	Α
I _{SM}	Pulsed Source Current ^{2,6}	V _G -V _D -0V , Force Current			40	Α
V_{SD}	Diode Forward Voltage ²	V_{GS} =0V , I_S =1A , T_J =25 $^{\circ}$ C			1.1	V
t _{rr}	Reverse Recovery Time			12		nS
Q _{rr}	Reverse Recovery Charge	IF=8A , dI/dt=100A/ μ s , T $_{J}$ =25 $^{\circ}$ C		3.5		nC

Note:

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper,t<10sec.
- 2.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3.The EAS data shows Max. rating . The test condition is $\rm V_{DD} = 25V, V_{GS} = 10V, L = 0.5mH, I_{AS} = 8A$
- 5. The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics

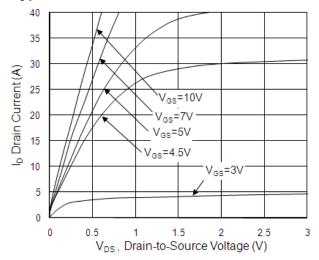


Fig.1 Typical Output Characteristics

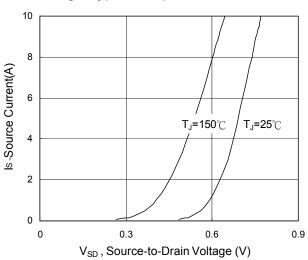
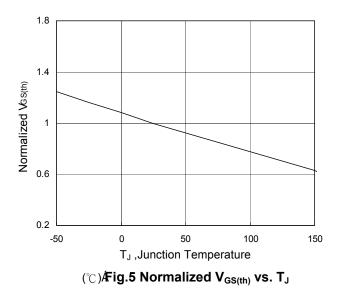


Fig.3 Forward Characteristics Of Reverse



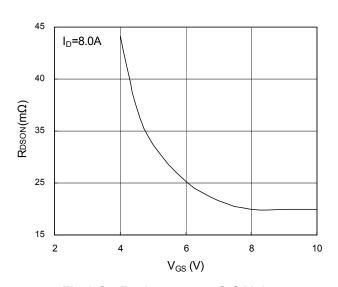


Fig.2 On-Resistance vs. G-S Voltage

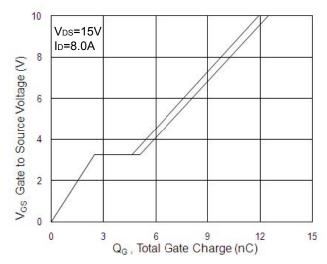


Fig.4 Gate-Charge Characteristics

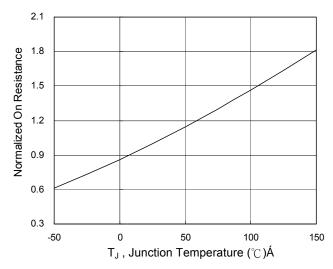
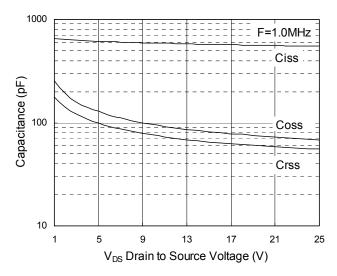


Fig.6 Normalized R_{DSON} vs. T_J





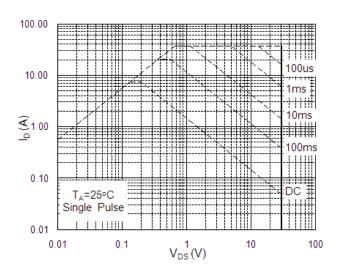


Fig.7 Capacitance

Fig.8 Safe Operating Area

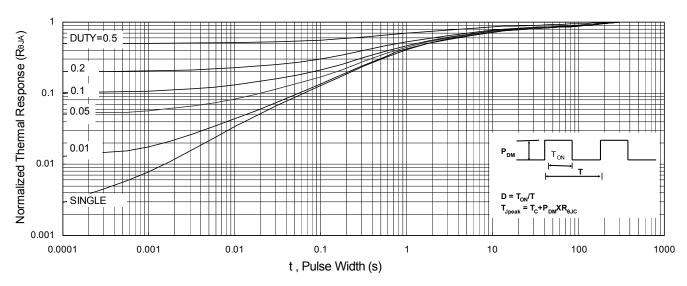


Fig.9 Normalized Maximum Transient Thermal Impedance

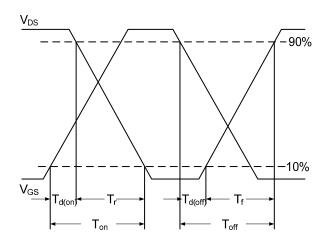


Fig.10 Switching Time Waveform

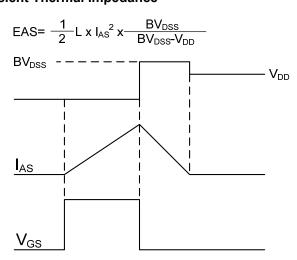
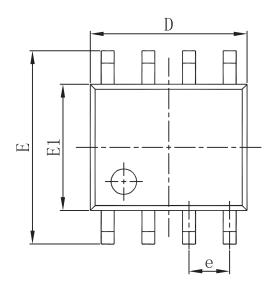
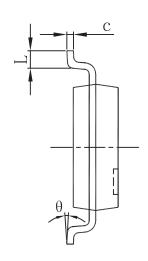


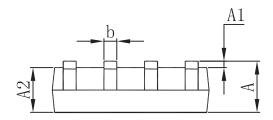
Fig.11 Unclamped Inductive Switching Waveform



Packaging information







Cross hoal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1. 350	1. 550	0. 053	0.061	
b	0.330	0. 510	0. 013	0.020	
С	0. 170	0. 250	0.007	0.010	
D	4.800	5. 000	0. 189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
Е	5. 800	6. 200	0. 228	0. 244	
E1	3.800	4. 000	0. 150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



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